

# CD74AC02, CD74ACT02

## Quad 2-Input NOR Gate

### Features

- **Typical Propagation Delay**
  - 6ns at  $V_{CC} = 5V$ ,  $T_A = 25^\circ C$ ,  $C_L = 50pF$
- **Exceeds 2kV ESD Protection MIL-STD-883, Method 3015**
- **SCR-Latchup-Resistant CMOS Process and Circuit Design**
- **Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption**
- **Balanced Propagation Delays**
- **AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply**
- **$\pm 24mA$  Output Drive Current**
  - Fanout to 15 FAST™ ICs
  - Drives 50 $\Omega$  Transmission Lines

### Description

The CD74AC02 and CD74ACT02 are quad 2-input NOR gates that utilize the Harris Advanced CMOS Logic technology.

### Ordering Information

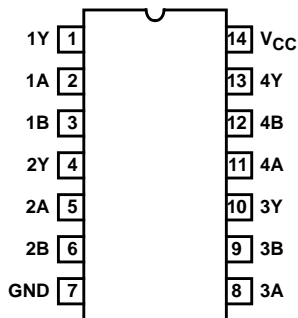
PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74AC02E	-55 to 125	14 Ld PDIP	E14.3
CD74ACT02E	-55 to 125	14 Ld PDIP	E14.3
CD74AC02M	-55 to 125	14 Ld SOIC	M14.15
CD74ACT02M	-55 to 125	14 Ld SOIC	M14.15

#### NOTES:

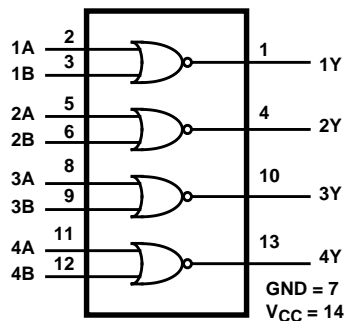
- When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Wafer and die for this part number is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

### Pinout

CD74AC02, CD74ACT02  
(PDIP, SOIC)  
TOP VIEW



### Functional Diagram



TRUTH TABLE

INPUTS		OUTPUTS
A	B	Y
L	L	H
H	L	L
L	H	L
H	H	L

## CD74AC02, CD74ACT02

### Absolute Maximum Ratings

DC Supply Voltage,  $V_{CC}$  ..... -0.5V to 6V  
 DC Input Diode Current,  $I_{IK}$   
     For  $V_I < -0.5V$  or  $V_I > V_{CC} + 0.5V$  .....  $\pm 20mA$   
 DC Output Diode Current,  $I_{OK}$   
     For  $V_O < -0.5V$  or  $V_O > V_{CC} + 0.5V$  .....  $\pm 50mA$   
 DC Output Source or Sink Current per Output Pin,  $I_O$   
     For  $V_O > -0.5V$  or  $V_O < V_{CC} + 0.5V$  .....  $\pm 50mA$   
 DC  $V_{CC}$  or Ground Current,  $I_{CC}$  or  $I_{GND}$  (Note 3) .....  $\pm 100mA$

### Thermal Information

Thermal Resistance (Typical, Note 5)  $\theta_{JA}$  ( $^{\circ}C/W$ )  
     PDIP Package ..... 90  
     SOIC Package ..... 175  
 Maximum Junction Temperature (Plastic Package) .....  $150^{\circ}C$   
 Maximum Storage Temperature Range .....  $-65^{\circ}C$  to  $150^{\circ}C$   
 Maximum Lead Temperature (Soldering 10s) .....  $300^{\circ}C$

### Operating Conditions

Temperature Range,  $T_A$  .....  $-55^{\circ}C$  to  $125^{\circ}C$   
 Supply Voltage Range,  $V_{CC}$  (Note 4)  
     AC Types ..... 1.5V to 5.5V  
     ACT Types ..... 4.5V to 5.5V  
 DC Input or Output Voltage,  $V_I$ ,  $V_O$  ..... 0V to  $V_{CC}$   
 Input Rise and Fall Slew Rate,  $dt/dv$   
     AC Types, 1.5V to 3V ..... 50ns (Max)  
     AC Types, 3.6V to 5.5V ..... 20ns (Max)  
     ACT Types, 4.5V to 5.5V ..... 10ns (Max)

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

#### NOTES:

14. For up to 4 outputs per device, add  $\pm 25mA$  for each additional output.
15. Unless otherwise specified, all voltages are referenced to ground.
16.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

### DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS		V <sub>CC</sub> (V)	25°C		-40°C TO 85°C		-55°C TO 125°C		UNITS
		V <sub>I</sub> (V)	I <sub>O</sub> (mA)		MIN	MAX	MIN	MAX	MIN	MAX	
AC TYPES											
High Level Input Voltage	V <sub>IH</sub>	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

# CD74AC02, CD74ACT02

## DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V <sub>CC</sub> (V)	25°C		-40°C TO 85°C		-55°C TO 125°C		UNITS
		V <sub>I</sub> (V)	I <sub>O</sub> (mA)		MIN	MAX	MIN	MAX	MIN	MAX	
Low Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	I <sub>I</sub>	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μA
Quiescent Supply Current SSI	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	-	4	-	40	-	80	μA
<b>ACT TYPES</b>											
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	I <sub>I</sub>	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μA
Quiescent Supply Current SSI	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	-	4	-	40	-	80	μA
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	ΔI <sub>CC</sub>	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

### NOTES:

- Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- Test verifies a minimum 50Ω transmission-line-drive capability at 85°C, 75Ω at 125°C.

### ACT Input Load Table

INPUT	UNIT LOAD
All	0.32

NOTE: Unit load is ΔI<sub>CC</sub> limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

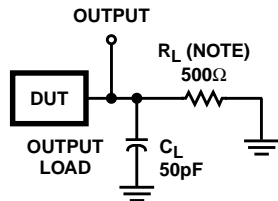
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## Switching Specifications Input $t_r, t_f = 3\text{ns}$ , $C_L = 50\text{pF}$ (Worst Case)

PARAMETER	SYMBOL	V <sub>CC</sub> (V)	-40°C TO 85°C			-55°C TO 125°C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
AC TYPES									
Propagation Delay, Input to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	131	-	-	144	ns
		3.3 (Note 9)	4.1	-	14.6	4	-	16.1	ns
		5 (Note 10)	3	-	10.4	2.9	-	11.5	ns
Input Capacitance	C <sub>I</sub>	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	55	-	-	55	-	pF
ACT TYPES									
Propagation Delay, Input to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	5 (Note 10)	3.1	-	11.1	3.1	-	12.2	ns
Input Capacitance	C <sub>I</sub>	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	55	-	-	55	-	pF

### NOTES:

19. Limits tested at 100%.
20. 3.3V Min at 3.6V, Max at 3V.
21. 5V Min at 5.5V, Max at 4.5V.
22.  $C_{PD}$  is used to determine the dynamic power consumption per gate.  
 AC:  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$   
 ACT:  $P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC}$  where  $f_i$  = input frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.



NOTE: For AC Series Only: When  $V_{CC} = 1.5\text{V}$ ,  $R_L = 1\text{k}\Omega$ .

	CD74AC	CD74ACT
Input Level	$V_{CC}$	3V
Input Switching Voltage, $V_S$	$0.5 V_{CC}$	1.5V
Output Switching Voltage, $V_S$	$0.5 V_{CC}$	$0.5 V_{CC}$

FIGURE 2. PROPAGATION DELAY TIMES

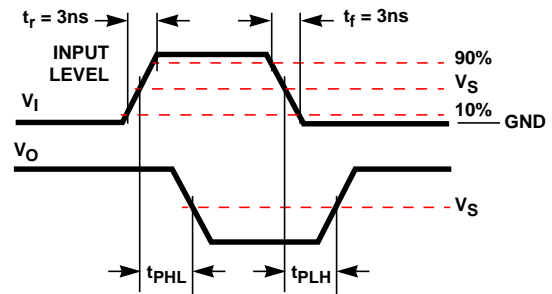


FIGURE 3. PROPAGATION DELAY TIMES

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